

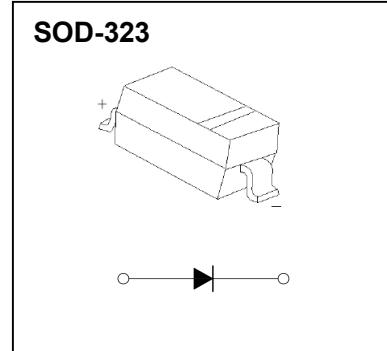


SOD-323 Plastic-Encapsulate Diodes

BAT60B SCHOTTKY BARRIER DIODE

FEATURES

- High Current Rectifier Schottky Diode with Low V_F Drop
- Low Voltage, Low Inductance
- For Power Supply
- For Detection and Step-up-Conversion



MARKING: W5 •

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_R	DC Blocking Voltage	10	V
I_F	Forward Current	3	A
I_{FSM}	Surge Forward Current($t<10\text{ms}$)	5	
P_D	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	286	$^\circ\text{C}/\text{W}$
T_J	Junction Temperature	125	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=1\text{mA}$	10			V
Reverse current	I_R	$V_R=5\text{V}$			15	μA
		$V_R=8\text{V}$			25	μA
Forward voltage	V_F	$I_F=100\text{mA}$			0.38	V
		$I_F=500\text{mA}$			0.5	
		$I_F=1000\text{mA}$			0.6	
Total capacitance	C_{tot}	$V_R=5\text{V}, f=1\text{MHz}$			30	pF